600mA / 15V Digital transistors (with built-in resistors)

DTC314TU / DTC314TK / DTC314TS

●Applications

Muting, Inverter, Interface, Driver

●Features

In addition to the features of regular digital transistors,

1) Low saturation voltage, typically $V_{CE(sat)}$=40mV at I_C/I_B=50mA/2.5mA, makes these transistors ideal for muting circuits.
2) These transistors can be used at high current levels, I_C=600mA.

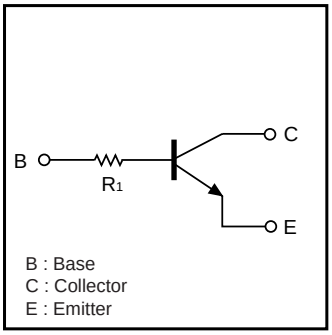
●Structure

NPN epitaxial planar silicon transistor
(Resistor built-in type)

●Packaging specifications

Part No.	Package	UMT3	SMT3	SPT
	Packaging type	Taping	Taping	Taping
	Code	T106	T146	TP
	Basic ordering unit (pieces)	3000	3000	5000
DTC314TU		○	–	–
DTC314TK		–	○	–
DTC314TS		–	–	○

●Equivalent circuit

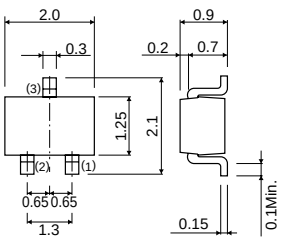


B : Base
C : Collector
E : Emitter

R_1=10kΩ

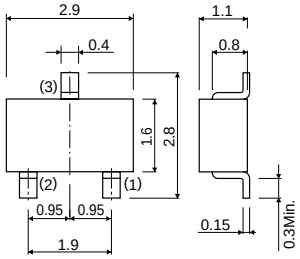
●External dimensions (Unit : mm)

DTC314TU



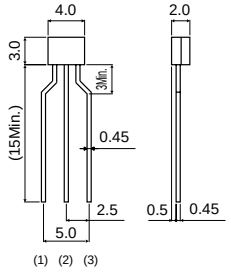
ROHM : UMT3
EIAJ : SC-70
Abbreviated symbol : H04
(1) Emitter
(2) Base
(3) Collector
Each lead has same dimensions

DTC314TK



ROHM : SMT3
EIAJ : SC-59
Abbreviated symbol : H04
(1) Emitter
(2) Base
(3) Collector
Each lead has same dimensions

DTC314TS



ROHM : SPT
EIAJ : SC-72
Abbreviated symbol : C314TS
(1) Emitter
(2) Collector
(3) Base

●**Absolute maximum ratings** (Ta=25°C)

Parameter	Symbol	Limits			Unit
		DTC314TU	DTC314TK	DTC314TS	
Collector-base voltage	V_{CBO}	30			V
Collector-emitter voltage	V_{CEO}	15			V
Emitter-base voltage	V_{EBO}	5			V
Collector current	I_C	600			mA
Collector power dissipation	P_C	200		300	mW
Junction temperature	Tj	150			°C
Storage temperature	Tstg	−55 to +150			°C

●**Electrical characteristics** (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV_{CBO}	30	–	–	V	I_C=50μA
Collector-emitter breakdown voltage	BV_{CEO}	15	–	–	V	I_C=1mA
Emitter-base breakdown voltage	BV_{EBO}	5	–	–	V	I_E=50μA
Collector cutoff current	I_{CBO}	–	–	0.5	μA	V_{CB}=20V
Emitter cutoff current	I_{EBO}	–	–	0.5	μA	V_{EB}=4V
Collector-emitter saturation voltage	$V_{CE(sat)}$	–	40	80	mV	I_C/I_B=50mA/2.5mA
DC current transfer ratio	h_{FE}	100	250	600	–	V_{CE}=5V, I_C=50mA
Input resistance	R_1	7	10	13	kΩ	–
Transition frequency	f_T *	–	200	–	MHz	V_{CE}=10V, I_E=−50mA, f=100MHz
Output "ON" resistance	R_{on}	–	1.25	–	Ω	V_I=7V, R_L=1kΩ, f=1kHz

* Characteristics of built-in transistor

●Electrical characteristic curves

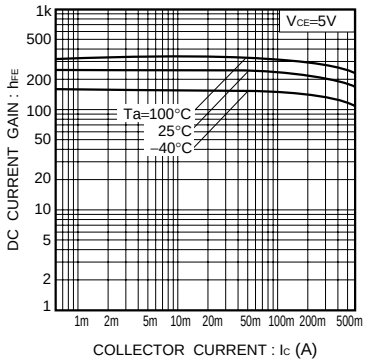


Fig.1 DC current gain vs. collector current

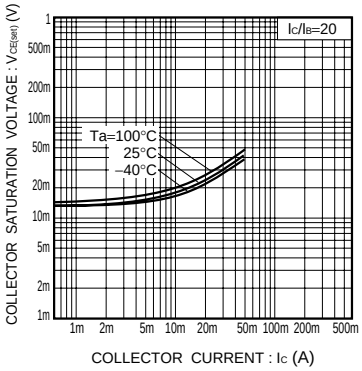


Fig.2 Collector-emitter saturation voltage vs. collector current

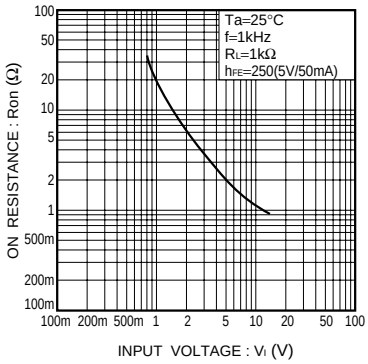


Fig.3 "ON" resistance vs. input voltage

●Ron measurement circuit

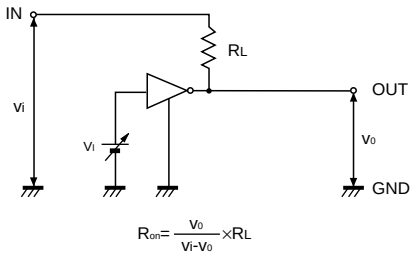


Fig.4 Output "ON" resistance (R_{on}) measurement circuit

Notes

- No technical content pages of this document may be reproduced in any form or transmitted by any means without prior permission of ROHM CO.,LTD.
- The contents described herein are subject to change without notice. The specifications for the product described in this document are for reference only. Upon actual use, therefore, please request that specifications to be separately delivered.
- Application circuit diagrams and circuit constants contained herein are shown as examples of standard use and operation. Please pay careful attention to the peripheral conditions when designing circuits and deciding upon circuit constants in the set.
- Any data, including, but not limited to application circuit diagrams information, described herein are intended only as illustrations of such devices and not as the specifications for such devices. ROHM CO.,LTD. disclaims any warranty that any use of such devices shall be free from infringement of any third party's intellectual property rights or other proprietary rights, and further, assumes no liability of whatsoever nature in the event of any such infringement, or arising from or connected with or related to the use of such devices.
- Upon the sale of any such devices, other than for buyer's right to use such devices itself, resell or otherwise dispose of the same, no express or implied right or license to practice or commercially exploit any intellectual property rights or other proprietary rights owned or controlled by
- ROHM CO., LTD. is granted to any such buyer.
- Products listed in this document are no antiradiation design.

The products listed in this document are designed to be used with ordinary electronic equipment or devices (such as audio visual equipment, office-automation equipment, communications devices, electrical appliances and electronic toys).
Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

About Export Control Order in Japan

Products described herein are the objects of controlled goods in Annex 1 (Item 16) of Export Trade Control Order in Japan.
In case of export from Japan, please confirm if it applies to "objective" criteria or an "informed" (by MITI clause) on the basis of "catch all controls for Non-Proliferation of Weapons of Mass Destruction.